Monolithic Linear IC



No.3325

LA8510

Telephonic Speech Network

### Overview

The Sanyo LA8510 Telephonic Speech Network provides amplification, switching and line drive functions for telephone equipment. It can perform 2 to 4 line conversion and impedance matching, and supports both DTMF and keytone signals.

The LA8510's low operating current reduces line load. Switching between the DTMF/keytone and voice circuits is controlled directly from a single MUTE input.

The LA8510 is available in plastic 20-pin DIPs.

#### Features

- · Direct connection to low-impedance receiver
- · DTMF/keytone and voice circuit switching controlled by a single MUTE input
- · Receive and transmit gain are adjusted automatically in response to the line current.
- · Applicable to a wide variety of transmitters and receivers by selecting external components.

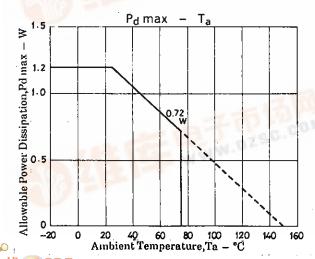
#### Maximum Ratings at Ta = 25°C

			V
Line Voltage	V <sub>L</sub> max	15	V
Line Current	I <sub>L</sub> max	150	mA
Allowable Power Dissipation	Pd max	1200	mW
Operating Temperature	Topr	-30  to  +75	$^{\circ}\mathrm{C}$
Storage Temperature	Tstg	-55  to  +150	$^{\circ}\mathrm{C}$

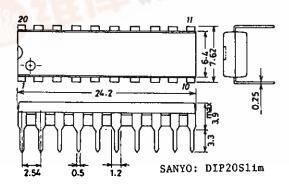
Operating Character	ristics at Ta = 25°C	f=1kHz,See specified Test Circuit.	min	typ	max	unit
Line Voltage	$ m V_L$	I <sub>L</sub> =20mA		3.2		V
		$I_L = 50 \text{mA}$		5.3		V
		$I_L = 120 \text{mA}$		10.6		V
Supply Voltage	$v_{cc}$	$I_L = 20 \text{mA}$		2.3		V
		$I_L = 50 \text{mA}$		4.0		V
		$I_L = 120 \text{mA}$		7.9		V

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unit

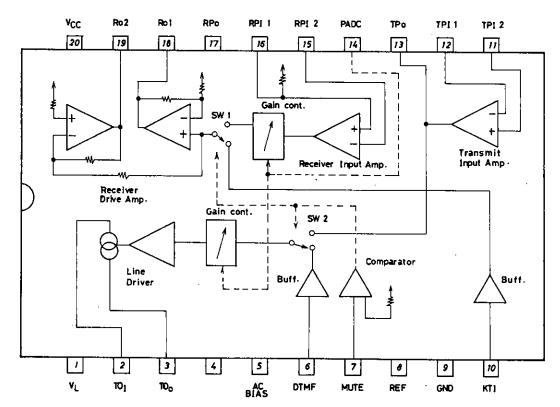


### Package Dimensions (unit: mm) 3021B

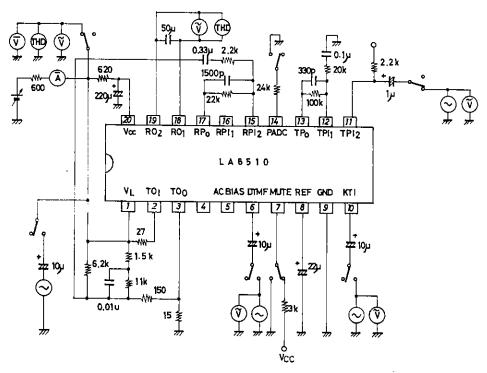


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			min	typ	max	unit
Transmit Gain	$G_{\mathbf{T}}$	$I_L = 20 \text{mA}, V_{IN} = -55 \text{dBV}$	38	40	42	dB
		$I_{L} = 120 \text{mA,V}_{IN} = -55 \text{dBV}$	35	37		dΒ
Receive Gain	$G_{R}$	$I_L = 20 \text{mA}, V_{IN} = -20 \text{dBV}$	7.5	10	12.5	dB
		$I_{L} = 120 \text{mA}, V_{IN} = -20 \text{dBV}$	1.5	4	6.5	dB
DTMF Gain	$G_{MF}$	$I_{L}=20 \text{mA}, V_{IN}=-30 \text{dBV}$	23	<b>2</b> 5	27	dB
		$I_L = 120 \text{ mA}, V_{IN} = -30 \text{dBV}$	20	22		' dB
Transmit Dynamic Range	$DR_T$	$I_L = 20 \text{mA,THD} = 4\%$	2.5			Vpp
		$I_L = 120 \text{mA,THD} = 4\%$	4.6			Vpp
Receive Dynamic Range	$DR_R$	$I_{L} = 20 \text{ mA,THD} = 10\%$	2.0			Vpp
·		$I_{L} = 120 \text{mA,THD} = 10\%$	6.0			Vpp
DTMF Input Impedance	$Z_{IMF}$	$I_L = 50 \text{mA}$	24			kΩ
KTI Input Impedance	$Z_{KTI}$	$I_L = 50 \text{mA}$	17			$k\Omega$
MUTE "H"-Level Input Voltage		$I_L = 20 \text{mA}$ to $120 \text{mA}$	1.5		$V_{CC}$	V
MUTE "L"-Level Input Voltage	$V_{IL}$	$I_{L} = 20 \text{mA to } 120 \text{mA}$	0		0.2	V
Transmit Attenuation	$\Delta G_{\mathrm{T}}$	$I_L = 30 \text{mA,PADC}$ grounded via $24 \text{k}\Omega$		3		dΒ
Receive Attenuation	$\Delta G_R$	$I_L = 30 \text{mA,PADC}$ grounded via $24 \text{k}\Omega$		6		dB
Reference Voltage	$V_{REF}$	$I_L = 20 \text{mA}$		0.7		V
•	•	$I_L = 50 \text{mA}$		1.3		V
	•	$I_L = 120 \text{mA}$		2.4		V
	Note)	Be careful of dielectric breakdown.				

# Equivalent Circuit Block Diagram

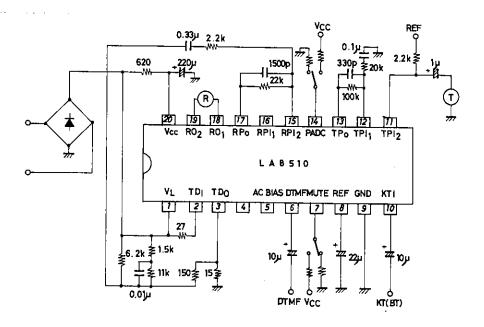


## **Test Circuit**



Unit (resistance:  $\Omega$ , capacitance: F)

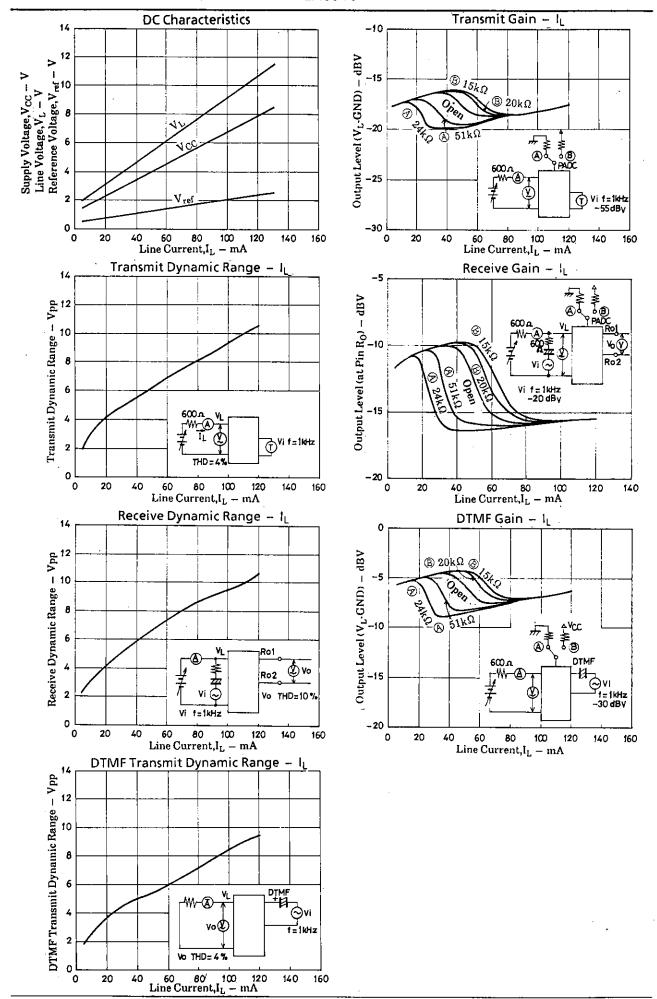
## Sample Application Circuit



Unit (resistance: Ω, capacitance: F)

## Pin Descriptions

Pin Number	Pin Name	Description
1	$V_{\rm L}$	Line voltage  Connected to the positive side of the line diode bridge. See the application circuit.
2	TO <sub>1</sub>	Transmit output current source, input side Connected to $V_L$ through a $27\Omega$ resistor. Select the value of this resistor after considering the maximum expected line current.
3	TOo	Transmit output current source, output side As above, but to ground through a $15\Omega$ resistor
4		Not used.  This pin has a DC bias and should not be connected.
5	AC BIAS	AC signal reference voltage An internally-generated reference voltage.
6	DTMF	DTMF input The signal on this pin is output on $V_L$ (pin 1) when MUTE (pin 7) is LOW. It should be decoupled using a capacitor since it is biased with the REF voltage.
7	MUTE	Mute control input Switches between the transmit side DTMF or receive side keytone, and voice circuits. LOW: DEMF output, keytone receive output HIGH: Voice circuits
8	REF	Reference voltage Internal amplifier bias voltage. Requires an external capacitor. This voltage should not be used by external circuitry.
9	GND	Ground Connected to the negative side of the line diode bridge.
10	кті	Key tone input  Switched through to the receive circuit output when MUTE (pin 7) is LOW. It should be decoupled using a capacitor since it is biased with REF voltage.
11	TPI <sub>2</sub>	Transmit input amp non-inverting input  Transmit voice circuit input. Requires a DC bias from REF (pin 8) through a resistor.
12	TPI <sub>1</sub>	Transmit input amp inverting input  Negative feedback input. Amplifier gain and frequency response are controlled by the feedback network.
13	TPO	Transmit input amp output
14	PADC	Pad control input $ \begin{tabular}{ll} \textbf{The value of the resistor between this pin and either $V_{CC}$ or ground determines the shape of the line-current vs. gain characteristics. See Electrical Characteristics.  \end{tabular}$
15	RPI <sub>2</sub>	Receive input amp inverting input  Negative feedback is applied from the amplifier output to control amplifier gain and frequency response.
16	RPI <sub>1</sub>	Receive input amp non-inverting input  This pin is internally biased through a resistor using REF.
17	RPo	Receive input amp output
18	R <sub>O1</sub>	Receive circuit output $BTL$ output. Connect a ceramic receiver between $R_{O1}$ and $R_{O2}$ .
19	R <sub>O2</sub>	1
20	V <sub>cc</sub>	Supply voltage Supply voltage for internal circuitry. This supply should not be used as an external circuit supply except as the high-level voltage for the MUTE and PADC inputs.



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